

## Electrical Characteristics

CHIP DIODES			PACKAGED DIODES							
Characteristics @ 25°C		Gold Ø	Breakdown voltage Vbr		Junction capacitance Cj2	Junction capacitance Cj-6 (1)		Series resistance Rsf	Minority carrier lifetime τl	
Test conditions			Ir = 10 μA		Vr = 0 V	Vr = 6V		If = 10mA	If = 10mA	
Type	Case		μm	V	pF	pF		Ω	ns	
		C2a	typ.	min.	max	typ.	min.	max	typ.	
EH60033			25			0.14	0.08	0.12	1.8	
EH60034			30			0.20	0.12	0.17	1.5	
EH60035			35	25	50	0.28	0.17	0.23	1.0	
EH60036			55			0.45	0.23	0.40	0.9	
EH60037			65			0.70	0.40	0.60	0.7	
EH60052		C2a	30			0.10	0.06	0.08	1.8	
EH60053			35			0.14	0.08	0.12	1.4	
EH60054			40			0.20	0.12	0.17	1.1	
EH60055			50	50	70	0.28	0.17	0.23	1.0	
EH60056			65			0.45	0.23	0.40	0.9	
EH60057			80			0.70	0.40	0.60	0.8	
EH60072		C2a	40			0.10	0.06	0.08	1.7	
EH60074			50	70	90	0.20	0.12	0.17	1.4	
EH60076			80			0.45	0.23	0.40	0.9	
EH60102		C2a	50			0.10	0.06	0.08	1.7	
EH60104			70	90	120	0.20	0.12	0.17	1.2	
EH60106			110			0.45	0.23	0.40	0.8	

(1) Other capacitance measurements available on request.

## Electrical Characteristics

PACKAGED DIODES			MICROWAVE CHARACTERISTICS					
Characteristics at 25°C			Thermal resistance Rth	Threshold PI	Leakage power POUT	Insertion loss	Peak power Ppin	CW power Ppin
Test conditions			Pdiss = 1W case F 27d	f = 2.7GHz 1dB Limiting	f = 2.7GHz	f = 2.7GHz P.pin = -10 dBm	Pulse= 1 μs DC =1%	
Type	Standard case (2)		°C/W max	dBm typ.	dBm typ.	dB typ.	dBm max	W max
	Cb = 0.18pF (3)	Cb = 0.12pF (3)						
DH60033	F 27d	M208	80	10	20	0.1	50	2.0
DH60034			80	10	20	0.1	50	2.0
DH60035			70	10	21	0.1	52	2.5
DH60036			60	10	22	0.2	53	3.0
DH60037			50	10	23	0.2	56	4.0
DH60052	F 27d	M208	80	15	24	0.1	52	2.5
DH60053			70	15	24	0.1	52	2.5
DH60054			60	15	25	0.1	53	3.0
DH60055			50	15	26	0.1	54	3.5
DH60056			45	15	27	0.2	57	4.0
DH60057			45	15	28	0.2	58	5.0
DH60072	F 27d	M208	70	18	27	0.1	54	3.0
DH60074			50	18	30	0.2	55	4.0
DH60076			40	18	32	0.2	58	5.0
DH60102	F 27d	M208	60	20	31	0.2	56	3.5
DH60104			50	20	33	0.2	59	5.0
DH60106			35	20	35	0.3	61	7.0

(2) Other capacitance measurements available on request.

(3) Ct = Cj + Cb